

EE Formula Sheet

Constants

$$\begin{aligned} q &= 1.602 \times 10^{-19} \text{ C} \\ m_e &= 9.109 \times 10^{-31} \text{ kg} \\ h &= 6.626 \times 10^{-34} \text{ J} \cdot \text{s} \\ k &= 1.381 \times 10^{-23} \text{ J/K} \\ \epsilon_0 &= 8.854 \times 10^{-12} \text{ C}^2/(\text{N} \cdot \text{m}^2) \\ c &= 3.00 \times 10^8 \text{ m/s} \\ e &\approx 1.6 \times 10^{-19} \text{ C} \\ kT &\approx 0.026 \text{ eV at } T = 300 \text{ K} \end{aligned}$$

Formulae

$$\begin{aligned} kT_{temp} &= 0.026 \left(\frac{temp}{300} \right), \text{ kT at a temperature temp} \\ \sigma &= en\mu_n + ep\mu_p, \text{ Conduction} \\ n_i^2 &= n_0 p_0, \text{ concentration at equilibrium} \\ n_i^2 &= n_c n_v e^{-E_g/kT}, \\ n_i^2 &\propto T^3 e^{-E_g/kT}, \text{ proportionality ratio} \\ n_i^2 \text{ at } 500 &= \left(\frac{500}{300} \right)^3 e^{-E_g/kT \text{ at } 500} e^{E_g/kT \text{ at } 300}, \text{ proportional temp} \\ E &= \frac{hc}{\lambda}, \text{ energy of photon} \\ E_g &= E_c - E_v, \text{ Energy band gap} \\ f(E) &= \frac{1}{1 + e^{\frac{E - E_f}{kT}}}, \text{ Fermi-Dirac Distribution Function} \\ n &= N_c \cdot e^{-\frac{E_c - E_f}{kT}}, \text{ Electron carrier concentration} \\ p &= N_v \cdot e^{-\frac{E_f - E_v}{kT}}, \text{ Hole carrier concentration} \\ J_d &= q \cdot n \cdot \mu_n \cdot E, \text{ Drift Current} \\ J_n &= q \cdot D_n \cdot \frac{dn}{dx}, \text{ Diffusion Current} \\ E_g &= E_c - E_v, \text{ Energy-Band Gap (Eg)} \\ \frac{1}{m^*} &= \frac{1}{m_l} + \frac{1}{m_t}, \text{ Electron and Hole Effective Mass} \\ q &= 1.602 \times 10^{-19} \text{ C}, \text{ Charge of an Electron} \\ n &= N_c \cdot e^{-\frac{E_c - E_f}{kT}}, \text{ Electron Carrier Concentration} \\ p &= N_v \cdot e^{-\frac{E_f - E_v}{kT}}, \text{ Hole Carrier Concentration} \\ J_n &= q \cdot n \cdot \mu_n \cdot E, \text{ Drift Current Density for Electrons} \\ J_p &= q \cdot p \cdot \mu_p \cdot E, \text{ Drift Current Density for Holes} \\ J_n &= q \cdot D_n \cdot \frac{dn}{dx}, \text{ Diffusion Current Density for Electrons} \\ J_p &= q \cdot D_p \cdot \frac{dp}{dx}, \text{ Diffusion Current Density for Holes} \\ N_c &= 2 \left(\frac{2\pi m_e kT}{h^2} \right)^{3/2}, \text{ Density of States in the Conduction Band (Nc)} \\ N_v &= 2 \left(\frac{2\pi m_h kT}{h^2} \right)^{3/2}, \text{ Density of States in the Valence Band (Nv)} \\ P_0 &= n_i e^{\frac{E_{fi} - E_f}{kT}} \\ P_0 &= \frac{N_A - N_D}{2} + \sqrt{\left(\frac{N_A - N_D}{2} \right)^2 + n_i^2} \\ N_0 &= \frac{N_D - N_A}{2} + \sqrt{\left(\frac{N_D - N_A}{2} \right)^2 + n_i^2} \\ f_F(E) &= \frac{1}{1 + e^{\frac{E - E_f}{kT}}}, \text{ Fermi-Dirac Distribution Function} \end{aligned}$$

$$\begin{aligned} f_F(E) &= e^{\frac{-(E - E_f)}{kT}}, \text{ Boltzman Approximation when } E - E_f \gg kT \\ \mu_n &= \frac{q \cdot \tau_n}{m^*}, \text{ Electron Mobility} \\ \mu_p &= \frac{q \cdot \tau_p}{m^*}, \text{ Hole Mobility} \\ G &= \alpha \cdot I, \text{ Generation Rate of Electron-Hole Pairs} \\ R &= B \cdot np - A \cdot n_i^2, \text{ Recombination Rate} \\ \frac{\partial n}{\partial t} + \nabla \cdot \mathbf{J}_n &= G - R, \text{ Continuity Equation for Electron Current} \\ \frac{\partial p}{\partial t} - \nabla \cdot \mathbf{J}_p &= G - R, \text{ Continuity Equation for Hole Current} \\ P_0 + N_D &= n_0 + N_A, \text{ Charge neutrality} \\ J_{drf} &= en\mu_n E + ep\mu_p E = \sigma E, \text{ Total Drift} \\ I &= AJ_{drf}, \text{ Current} \\ E &= \text{Volt}/\text{Len}, \text{ Electric Field} \\ V_{dn} &= \mu_n E, \text{ Drift velocity for electrons} \\ V_{dp} &= \mu_p E, \text{ Drift velocity for holes} \end{aligned}$$

§EEO 311

$$\begin{aligned} A_v &= \frac{V_{out}}{V_{in}}, \text{ Voltage Gain Formula} \\ |A_v| &= gmR_D, \\ A_v &= \frac{R_D}{1/gm}, \\ V_{ov} &= V_{bias} - V_{th}, \text{ Overdrive Voltage} \\ gm &= K_n' \frac{W}{L} V_{ov}, \text{ transconductance parameter} \\ gm &= \frac{2ID}{V_{ov}} \\ ID &= \frac{1}{2} gm V_{ov}, \text{ Drain Current Equation} \\ ID &= \frac{1}{2} K_n' \frac{W}{L} V_{ov}^2, \text{ Drain Current Equation} \\ V_{ov} &= \frac{ID}{K_n' \frac{W}{L}}, \text{ Overdrive voltage} \\ ID &= gm \cdot V_{gs}, \text{ Drain current} \\ ID &= \frac{V_{DD}}{R_D}, \text{ Drain current} \\ gm &= \frac{\Delta ID}{\Delta V_{GS}} = K_n' \frac{W}{L} V_{ov}, \\ V_{DD} &= V_{DS} + ID \cdot R_D, \text{ Load line equation} \\ V_{DD} &= V_{DS} + ID \cdot R_D, \text{ Load line equation} \\ r_o &= \frac{V_A}{ID}, \text{ Early voltage } V_A \\ V_A' &= \frac{V_A}{L}, \text{ early voltage process parameter} = 20 \text{ V}/\mu\text{m} \\ A_o &= gm \cdot r_o, \text{ Intrinsic gain for bjt and mosfet} \\ A_o &= \frac{2V_A}{V_{ov}}, \text{ Intrinsic gain} \\ A_o &= \frac{2V_A L}{V_{ov}}, \text{ Intrinsic gain} \end{aligned}$$

Proportionalities

$$ID \propto V_{ov}^2, \text{ drain current and overdrive voltage proportionality}$$

§1.2 - The PN Junction

Notes

Common Source: Input connected to gate, output connected to drain.

Common Drain (Source Follower): Input connected to gate, output connected to source.

Common Gate: Input connected to source, output connected to drain.

When $N_A \gg N_D$, the semiconductor is p-type.

When $N_D \gg N_A$, the semiconductor is n-type.

BJT Amplifier

$$\begin{aligned} g_m &= 2\sqrt{K_n I_{DQ}}, \\ g_m &= \frac{I_D}{V_{GS}}, \\ g_m &= 2K_n (V_{GS} - V_{TH}), \\ g_m &= \frac{I_C}{V_{TH}}, \\ g_m &= \frac{I_C}{V_T}, \\ r_o &= \frac{1}{\lambda I_{DQ}}, \\ r_o &= \frac{V_A}{I_C}, \\ r_\pi &= \frac{V_T}{I_B}, \\ r_\pi &= \frac{\beta}{g_m}, \\ A_v &= -g_m \cdot R_C || R_L, \text{ Voltage Gain Formula} \end{aligned}$$

Transistor DC Equivalent

$$\begin{aligned} V_{th} &= \frac{V_{cc}}{R_1 + R_2} \cdot R_2, \\ R_{th} &= R_1 || R_2, \\ V_{ce(sat)} &\approx 0.2(\text{typ}), \\ I_E &\approx I_C, \text{ In active region} \\ -\frac{1}{R_E - R_C}, &\text{ load line slope, where } R_C \text{ \& } R_E \text{ are from the AC or DC equivalent circuit. A load line plot is } I_C \text{ vs } V_{CE} \\ I_{RE} &= I_B(\beta + 1)R_E, \end{aligned}$$

Transistor formulas

$$\begin{aligned} I_C &= \beta \cdot I_B, \text{ Conduction Parameter} \\ I_C &= I_S e^{\frac{V_{BE}}{V_T}}, \\ I_B &= \frac{I_E}{\beta + 1}, \\ \alpha &= \frac{I_C}{I_E}, \text{ Current Ratio} \\ I_C &= I_E - I_B, \text{ Kirchhoff's Current Law} \\ V_{CE} &= V_{BE} + V_{CB}, \text{ Voltage Relationships} \\ I_C &= I_{C0} \left(e^{\frac{V_{BE}}{V_T}} - 1 \right), \text{ BJT Current Equation} \\ I &= I_0 \cdot \left(e^{\frac{V}{n \cdot V_T}} - 1 \right), \text{ Schottky Diode Equation} \\ ID &= \frac{1}{2} \mu_n C_{ox} \frac{W}{L} (V_{GS} - V_{TH})^2, \text{ MOSFET Drain Current Equation} \end{aligned}$$

$$ID = \mu_n C_{ox} \frac{W}{L} \left[(V_{GS} - V_{TH}) V_{DS} - \frac{V_{DS}^2}{2} \right], \text{ MOSFET Drain Current Equation (Triode Region)}$$

$$\begin{aligned} g_m &= \sqrt{2\mu_n C_{ox} \frac{W}{L}} ID, \text{ Transconductance Parameter} \\ A_v &= -g_m \cdot R_D, \text{ Voltage Gain Formula} \end{aligned}$$

MOS Field-Effect Transistor

N-Channel

$v_{DS(sat)} = v_{GS} - V_{TN}$, Saturation Voltage, where V_{TN} is the threshold voltage.

$i_D = K_n [2(v_{GS} - V_{TN})v_{DS} - v_{DS}^2]$, I-V Characteristic in non-saturation.

$i_D = K_n (v_{GS} - V_{TN})^2$, I-V Characteristic in saturation.

$C_{ox} = \epsilon_{ox}/t_{ox}$, Oxide capacitance per unit area.

$\epsilon_{ox} = (3.9)(8.85 \times 10^{-14} \text{ F/cm})$, Oxide permittivity for Si devices.

$$K_n = \frac{W \mu_n C_{ox}}{2L}, \text{ Conduction Parameter}$$

$K_n = \frac{k'_n}{2} \cdot \frac{W}{L}$, Conduction Parameter
 $k'_n = \mu_n C_{ox}$, Process conduction parameter.
 μ_n , Electron mobility in the inversion layer.

P-Channel

$i_D = K_p [2(v_{SG} - V_{TP})v_{SD} - v_{SD}^2]$, I-V Characteristic in non-saturation.

$i_D = K_p (v_{SG} - V_{TP})^2$, I-V Characteristic in saturation.

$K_p = \frac{W\mu_p C_{ox}}{2L}$, Conduction Parameter

$K_p = \frac{k'_p}{2} \cdot \frac{W}{L}$, Conduction Parameter
 $k'_p = \mu_p C_{ox}$

EE General Formulae

$rms = \frac{1}{\sqrt{2}}$,
 $V = I \cdot R$, Ohm's law.
 $P = V \cdot I$, DC Power.
 $P = V \cdot I \cdot \cos(\theta)$, AC power.
 $E = P \cdot t$, Energy.
 $C = \frac{Q}{V}$, Capacitance.
 $V = L \cdot \frac{di}{dt}$, Inductance.
 $\tau = R \cdot C$, Time constant to reach 63.2% of capacitors final voltage.
 $\tau = \frac{L}{R}$, Time constant to reach 63.2% of inductors final value.
 $\frac{N_1}{N_2} = \frac{V_1}{V_2}$, Transformer turns ratio.
 $V_{peak} = \sqrt{2} \cdot V_{rms}$, Peak AC Voltage.
 $V_{rms} = \frac{V_{peak}}{\sqrt{2}}$, RMS AC Voltage.
 $V_{avg} = \frac{1}{T} \int_0^T V(t) dt$, RMS AC Voltage.
 $V_{out} = V_{in} \cdot \frac{R_2}{R_1 + R_2}$, voltage divider.
 $R_{eq} = R_1 + R_2 + \dots + R_n$, series resistors.
 $\frac{1}{R_{eq}} = \frac{1}{R_1} + \frac{1}{R_2} + \dots + \frac{1}{R_n}$, Parallel resistors.
 $\frac{1}{C_{eq}} = \frac{1}{C_1} + \frac{1}{C_2} + \dots + \frac{1}{C_n}$, Series capacitors.
 $C_{eq} = C_1 + C_2 + \dots + C_n$, parallel capacitors.

Convert Polar to Rectangular

$$x = r \cos \theta$$

$$y = r \sin \theta$$

Exact Slope of a Tangent Line

$$\frac{dy}{dx} = \frac{dy/dt}{dx/dt}$$

Basic integration Rules

$\int k f(u) du = k \int f(u) du + C$,
 $\int [f(u) \pm g(u)] du = \int f(u) du \pm \int g(u) du$, $\int du = u + C$,
 $\int u^n du = \frac{u^{n+1}}{n+1} + C, n \neq -1$, $\int \frac{du}{u} = \ln |u| + C$,
 $\int \frac{u}{du} = \frac{u^2}{2} + C$, $\int e^u du = e^u + C$, $\int e^{4u} = \frac{e^{4u}}{4} + C$,
 $\int a^u du = \left(\frac{1}{\ln a}\right) a^u + C$,

Some Integrals

$\int \sin u du = -\cos u + C$, $\int \cos u du = \sin u + C$,
 $\int \tan u du = -\ln |\cos u| + C$, $\int \cot u du = \ln |\sin u| + C$,
 $\int \sec u du = \ln |\sec u + \tan u| + C$,
 $\int \csc u du = -\ln |\csc u + \cot u| + C$, $\int \sec^2 u du = \tan u + C$,
 $\int \csc^2 u du = -\cot u + C$, $\int \sec u \tan u du = \sec u + C$,
 $\int \csc u \cot u du = -\csc u + C$, $\int \frac{du}{\sqrt{a^2 - u^2}} = \arcsin \frac{u}{a} + C$,

$\int \frac{du}{a^2 + u^2} = \frac{1}{a} \arctan \frac{u}{a} + C$, $\int \frac{du}{u\sqrt{u^2 - a^2}} = \frac{1}{a} \operatorname{arcsec} \frac{|u|}{a} + C$,

$\int \sin 3x = -\frac{1}{3} \cos 3x$, $\int e^{-4x} = \frac{e^{-4x}}{-4}$

$\int k dx = kx + C$, $\int x dx = \frac{1}{2} x^2 + C$, $\int x^2 dx = \frac{1}{3} x^3 + C$,
 $\int \frac{1}{x} dx = \ln |x| + C$, $\int e^x dx = e^x + C$, $\int k^u du = \frac{k^u}{\ln k} + C$,
 $\int \ln x dx = x \ln x - x + C$, $\int \cos x dx = \sin x + C$,
 $\int \sin x dx = -\cos x + C$, $\int \sec^2 x dx = \tan x + C$,
 $\int x^n dx = \frac{x^{n+1}}{n+1} + C$, $\int \tan x = -\ln(\cos x) + C$,

Integration by Parts

$$\int u dv = uv - \int v du$$

Some Identities

$$\sin 2x = 2 \sin x \cos x$$

Pythagorean:

$$\sin^2 x + \cos^2 x = 1, 1 + \tan^2 x = \sec^2 x, 1 + \cot^2 x = \csc^2 x$$

Reciprocal:

$$\sin x = \frac{1}{\csc x}, \cos x = \frac{1}{\sec x}, \tan x = \frac{\sin x}{\cos x} = \frac{1}{\cot x}$$

$$\csc x = \frac{1}{\sin x}, \sec x = \frac{1}{\cos x}, \cot x = \frac{\cos x}{\sin x} = \frac{1}{\tan x}$$

Half Angle:

$$\sin^2 x = \frac{1}{2}(1 - \cos 2x), \cos^2 x = \frac{1}{2}(1 + \cos 2x)$$

Additional Notes:

$$\ln(x * y) = \ln(x) + \ln(y), \ln(x/y) = \ln(x) - \ln(y)$$

$$\ln x^a = a \ln x, \tan \theta = \frac{\sin \theta}{\cos \theta}$$

$$ax^2 + bx + c = 0, x = \frac{-b \pm \sqrt{b^2 - 4ac}}{2a}$$

$$\ln a = c \equiv e^c = a$$

$$\sqrt[n]{a} = a^{\frac{1}{n}}, a^{-n} = \frac{1}{a^n}, \sqrt[n]{a^m} = a^{\frac{m}{n}}, a^0 = 1, (a^m)^n = a^{mn},$$

$$a^m * a^n = a^{m+n}, \frac{a^m}{a^n} = a^{m-n}, \text{ Rewrite } \sqrt{5}x \text{ as } \sqrt{5}\sqrt{x},$$

Some Derivatives:

$$\frac{d}{du} \sin u = (\cos u)u', \frac{d}{du} \cos u = -(\sin u)u',$$

$$\frac{d}{du} \tan u = (\sec^2 u)u', \frac{d}{du} \cot u = -(\csc^2 u)u',$$

$$\frac{d}{du} \sec u = (\sec u \tan u)u', \frac{d}{du} \csc u = -(\csc u \cot u)u',$$

$$\frac{d}{du} \arcsin u = \frac{u'}{\sqrt{1-u^2}}, \frac{d}{du} \arccos u = \frac{-u'}{\sqrt{1-u^2}},$$

$$\frac{d}{du} \arctan u = \frac{u'}{1+u^2}, \frac{d}{du} \operatorname{arccot} u = \frac{-u'}{1+u^2},$$

$$\frac{d}{du} \operatorname{arcsec} u = \frac{u'}{|u|\sqrt{u^2-1}}, \frac{d}{du} \operatorname{arccsc} u = \frac{-u'}{|u|\sqrt{u^2-1}}$$

$$\frac{d}{du} [\ln u] = \frac{1}{u}u', \frac{d}{dx} [e^{-x}] = -e^{-x}, e^{\ln a} = a$$

$$\frac{d}{du} [\sqrt{u}] = \frac{u'}{2\sqrt{u}}, e^{3x} = 3e^{3x}, \frac{d}{dx} [x] = 1, \frac{d}{dx} [c] = 0,$$

$$\frac{d}{du} \left[\frac{1}{u}\right] = \frac{1}{u^2}, \frac{du}{u} = \ln |u|,$$

